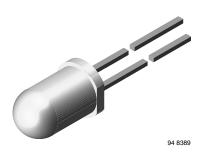
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**Vishay Semiconductors** 

# Infrared Emitting Diode, 875 nm, GaAlAs



### DESCRIPTION

The TSHA6500 is an infrared, 875 nm emitting diode in GaAlAs technology, molded in a clear, untinted plastic package.

### **FEATURES**

- Package type: leaded
- Package form: T-1¾
- Dimensions (in mm): Ø 5
- Peak wavelength:  $\lambda_p = 875 \text{ nm}$
- High reliability
- Angle of half intensity:  $\varphi = \pm 24^{\circ}$
- Low forward voltage
- · Suitable for high pulse current operation
- · Good spectral matching with Si photodetectors
- Compliant to RoHS Directive 200/95/EC and in accordance to WEEE 2002/96/EC

#### Note

\*\* Please see document "Vishay Material Category Policy": www.vishay.com/doc?99902

### **APPLICATIONS**

- Infrared remote control and free air data transmission systems with comfortable radiation angle
- This emitter is dedicated to systems with panes in transmission space between emitter and detector, because of the low absorbtion of 875 nm radiation in glass

PRODUCT SUMMARY				
COMPONENT	l <sub>e</sub> (mW/sr)	φ (deg)	λ <sub>P</sub> (nm)	tr (ns)
TSHA6500	30	± 24	875	600

#### Note

Test conditions see table "Basic Characteristics"

ORDERING INFORMATI	ON		
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM
TSHA6500	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	T-1¾

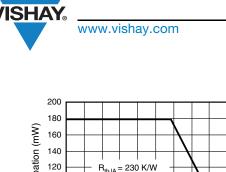
#### Note

• MOQ: minimum order quantity

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V <sub>R</sub>	5	V	
Forward current		I <sub>F</sub>	100	mA	
Peak forward current	t <sub>p</sub> /T = 0.5, t <sub>p</sub> = 100 μs	I <sub>FM</sub>	200	mA	
Surge forward current	t <sub>p</sub> = 100 μs	I <sub>FSM</sub>	2.5	А	
Power dissipation		Pv	180	mW	
Junction temperature		Тj	100	°C	
Operating temperature range		T <sub>amb</sub>	- 40 to + 85	°C	
Storage temperature range		T <sub>stg</sub>	- 40 to + 100	°C	
Soldering temperature	$t \le 5$ s, 2 mm from case	T <sub>sd</sub>	260	°C	
Thermal resistance junction/ambient	J-STD-051, leads 7 mm, soldered on PCB	R <sub>thJA</sub>	230	K/W	







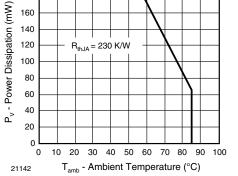


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

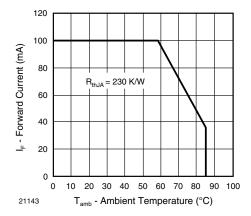


Fig. 1 - Forward Current Limit vs. Ambient Temperature

<b>BASIC CHARACTERISTICS</b> ( $T_{amb} = 25 \text{ °C}$ , unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I <sub>F</sub> = 100 mA, t <sub>p</sub> = 20 ms	V <sub>F</sub>		1.5	1.8	V
	I <sub>F</sub> = 1 A, t <sub>p</sub> = 100 μs	V <sub>F</sub>		2.8	3.5	V
Temperature coefficient of $V_F$	I <sub>F</sub> = 100 mA	TK <sub>VF</sub>		- 1.6		mV/K
Reverse current	V <sub>R</sub> = 5 V	I <sub>R</sub>			100	μA
Junction capacitance	V <sub>R</sub> = 0 V, f = 1 MHz, E = 0	Cj		20		pF
<b>—</b> • • • • •	I <sub>F</sub> = 100 mA, t <sub>p</sub> = 20 ms	l <sub>e</sub>	16	30	48	mW/sr
Radiant intensity	I <sub>F</sub> = 1 A, t <sub>p</sub> = 100 μs	l <sub>e</sub>	128	240		mW/sr
Radiant power	I <sub>F</sub> = 100 mA, t <sub>p</sub> = 20 ms	φe		24		mW
Temperature coefficient of $\phi_{\text{e}}$	I <sub>F</sub> = 20 mA	TKφ <sub>e</sub>		- 0.7		%/K
Angle of half intensity		φ		± 24		deg
Peak wavelength	I <sub>F</sub> = 100 mA	λρ		875		nm
Spectral bandwidth	I <sub>F</sub> = 100 mA	Δλ		80		nm
Temperature coefficient of $\lambda_p$	I <sub>F</sub> = 100 mA	ΤΚλρ		0.2		nm/K
Dia a tina a	I <sub>F</sub> = 100 mA	t <sub>r</sub>		600		ns
Rise time	I <sub>F</sub> = 1 A	t <sub>r</sub>		300		ns
<b>F W C</b>	I <sub>F</sub> = 100 mA	t <sub>f</sub>		600		ns
Fall time	I <sub>F</sub> = 1 A	t <sub>f</sub>		300		ns
Virtual source diameter		d		2.2		mm



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## BASIC CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

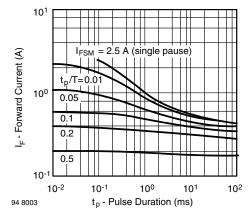


Fig. 2 - Pulse Forward Current vs. Pulse Duration

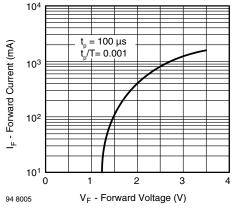


Fig. 3 - Forward Current vs. Forward Voltage

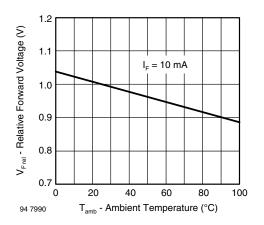


Fig. 4 - Relative Forward Voltage vs. Ambient Temperature

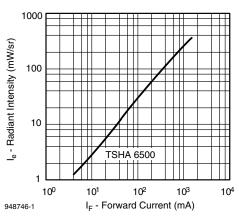
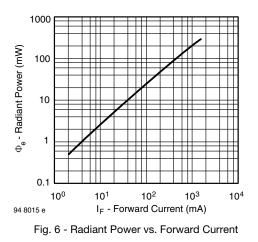


Fig. 5 - Radiant Intensity vs. Forward Current



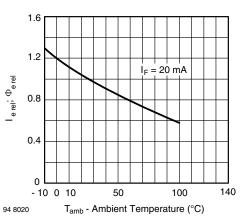
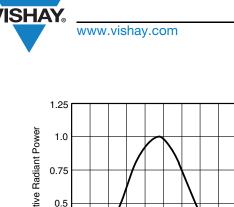
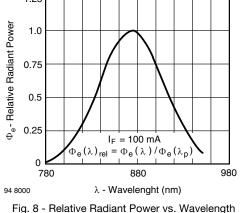


Fig. 7 - Relative Radiant Intensity/Power vs. Ambient Temperature

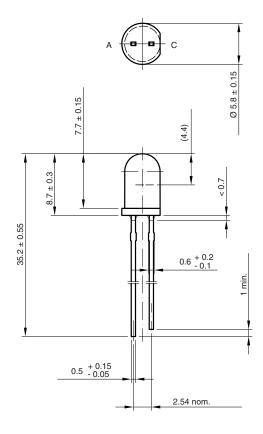
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## **PACKAGE DIMENSIONS** in millimeters



6.544-5259.08-4 Issue: 3; 19.05.09 14436

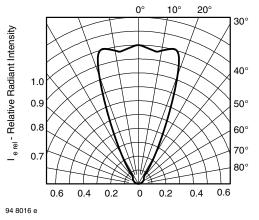
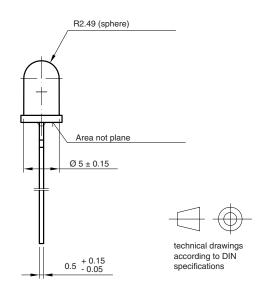


Fig. 9 - Relative Radiant Intensity vs. Angular Displacement



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